

Nanocomposites of embedded Fe nanoparticles in CrN films for enhanced thermoelectric properties

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Abstract

Nanostructuring and nanocomposites have shown great potential for improving the efficiency of thermoelectric materials. Using physical vapor deposition techniques, nanocomposites composed of Fe nanoparticles embedded into a CrN matrix were produced. By using a combinatorial process of high-power impulse magnetron sputtering and a so-called nanoparticle gun, multilayer nanocomposite coatings were deposited. This combinatorial technique allowed the formation of nanocomposites in which the Fe nanoparticles remained intact without reaction with the matrix. The measured thermoelectric properties of the coatings revealed an increase in the Seebeck coefficient, with a decrease in the electrical conductivity after insertion of Fe nanoparticle. This change of behavior has been correlated to the variation of charge carrier concentration and electron mobility. This study shows the potential of the nanocomposite synthesis process and its use in improving the thermoelectric properties of coatings.

Introduction

Thermoelectric thin films have shown potential with a role as waste heat recovery and microdevices refrigeration [1]. The conversion efficiency of certain thermoelectric devices is governed by the dimensionless figure of merit, $ZT = (S^2 \sigma) / \kappa$, where S is the Seebeck coefficient, σ is the electrical conductivity and κ is the thermal conductivity [2]. Several strategies are used to improve thermoelectric performance, including the search for new materials or optimization of existing ones by doping, alloying, and/or nanoscale effects [2-5]. Nevertheless, the most prominent challenge for thermoelectricity is that the three physical parameters (S , σ , and κ) are strongly interdependent and coupled with the carrier concentration [5].

Transition metal nitride (ScN and CrN) material systems have shown potential for use as thermoelectric materials [6]. CrN-based materials can be n-type or p-type thermoelectric materials depending on doping and nitrogen stoichiometry [7-11]. The n-type CrN has a relatively high Seebeck coefficient, high electrical conductivity, and medium to low thermal conductivity [6, 7, 10]. Due to the presence of magnetic disorder in CrN [12], lower thermal conductivity ($\sim 2 - 3 \text{ W}\cdot\text{K}^{-1}\cdot\text{m}^{-1}$ @ RT [6, 11]) is reported for CrN compared to other transition metal nitrides with the same crystallographic structure ($10 - 22 \text{ W}\cdot\text{K}^{-1}\cdot\text{m}^{-1}$ @ RT [6, 13, 14]).

Several theoretical and experimental studies have suggested new horizons for improving the thermoelectric properties by phonon and carrier engineering using nanoparticle (NP) nanocomposite material [5, 7, 15-18]. The strategy is to decouple the physical (σ and κ) from the thermoelectric properties (S) which are normally interdependent [5, 16]. It was suggested that using soft-magnetic NPs dispersed in a semiconductor matrix would: i) reduce the thermal conductivity by insertion of defect combined by the Kondo-like effect for increased phonons scattering; ii) increase the Seebeck coefficient by electron filtering happening at the metal/semiconductor interface [19]; iii) increase the electrical conductivity by the modulation doping at the metal/semiconductor interfaces due to the difference in the work functions between matrix and inclusion [15].

The synthesis of nanocomposites using NPs remains challenging due to the thermodynamic aspects present between the selected NPs and the matrix. Few have reported the formation of nano-inclusion, generally undesirable, at first, to form a secondary phase which can be beneficial for the thermoelectric properties [7, 18, 20, 21]. To date there are very few works reporting nanocomposite film synthesis, in a controlled manner of fully inorganic NPs dispersed into a matrix where both materials would normally form a solid solution or intermix using conventional synthesis method.

In the present study, we explore an uncommon synthesis strategy, using physical vapor deposition for growing nanocomposite materials of Fe-NP in a CrN thermoelectric matrix. Using conventional synthesis methods, these two material systems would normally form a solid solution or intermix. Fe NPs were selected to maximize the thermal fluctuation of magnetic moment as it is the strongest soft-magnetic single element metal, in order to improve the thermoelectric properties of CrN. The multilayer coatings consist of CrN layers separated with dispersed Fe-NP which were deposited sequentially in the same deposition chamber. Using High power magnetron sputtering, crystalline CrN was deposited at room temperature while the NPs were synthesized using a nanoparticle cluster source in a so-called Nanoparticle gun (with differential pumping) using a hollow cathode target. For comparison, three coatings were deposited: a CrN film without NPs, and two multilayer coatings with different proportions of Fe-NPs. The effect of the Fe-NP insertion on the structure, morphology and thermoelectric properties of the coatings was investigated.

Methods

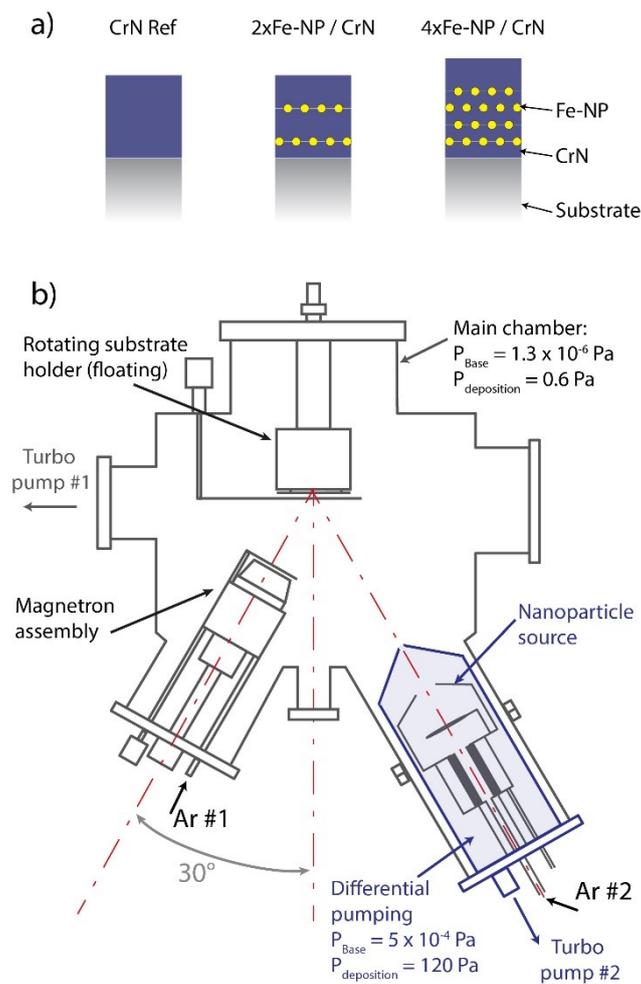


Figure 1: Schematic representations of (a) the multilayer nanocomposite coatings and (b) the deposition chamber with the magnetron assembly and the nanoparticle source in a secondary chamber.

Figure 1 presents an overview of the deposition chamber used for the deposition along with a schematic view of the multilayer coating designs. The CrN/Fe-NP coatings consisted of alternating CrN layers and dispersed Fe-nanoparticle layers. With a total thickness of 80-100nm, three different types of samples were deposited: i) a reference monolithic CrN film; ii) a multilayer coating with two “layers” of Fe-NP named 2xFe-NP/CrN film; iii) a multilayer coating with four layers of Fe-NP named 4xFe-NP/CrN film (Figure 1a). The thickness of each layer was controlled by deposition time where the bottom layer was kept constant at 15 nm and the top layer 30 nm. The layers of CrN between the Fe NP were 30 nm and 15 nm for the 2xfe-NP/CrN film and 4xfe-NP/CrN film, respectively.

The CrN thin film was deposited by high power impulse magnetron sputtering (HiPIMS) in an ultra-high vacuum chamber with a base pressure of 1.3×10^{-6} Pa using a 50 mm in diameter Cr target (Kurt J. Lesker / 99.95%). More details on the deposition chamber can be found elsewhere [22]. The chamber

was equipped with one magnetron and a nanoparticle source which was set in place of a second magnetron sputter position (Figure 1b). The magnetron sputter, situated at 135 mm from the substrate, was powered by a HiPIMS unit (HiPSTER 1, Ionautics AB) with an average target power of 50 W, an average peak current of 8.5 A, and fixed voltage, pulse length, pulse frequency at 500 V, 30 μ s, 700 Hz, respectively. The deposition conditions of the CrN layer were chosen to obtain pure NaCl-B1 phase at room temperature.

The nanoparticle source consists of a “secondary cylindrical chamber” with a 1 mm orifice directed toward the substrate and placed at 250 mm from the substrate. The “secondary cylindrical chamber” with an approximate volume of 0.00225 m³ (dimension: 26 cm x 10.5 cm \varnothing) had a differential pumping with a base pressure of 5×10^{-4} Pa (Figure 1b) in which a hollow cathode sputtering system was placed to produce NPs. Note here that the walls of the secondary chamber were electrically floating to avoid any disruption in the nanoparticle synthesis and deposition. The nanoparticle source (HIPNano Ionautics AB) was equipped with an Fe hollow cathode of $\varnothing_{\text{outer}}$ 9 mm/ $\varnothing_{\text{inner}}$ 5 mm x 54 mm (Good Fellow, 99.5 % purity), and the anode ring was fixed at 10 mm away from the hollow cathode. The hollow cathode was powered by a HiPIMS unit (HiPSTER 1, Ionautics AB) at a fixed average power of 20 W, fixed pulse length of 30 μ s, fixed pulse frequency of 300 Hz and an average peak current of 13 A and voltage of 485 V. The conditions of deposition and anode position in the nanoparticle source were selected to obtain Fe-NP of a size around 6-11 nm. To estimate the concentration and sizes of the nanoparticle in each NP “layer”, the deposition of the multilayer was stopped after the first NP “layer” deposited, and the surface morphology analyzed by SEM.

A gas mixture consisting of Ar of 16 sccm and N₂ of 55 sccm was inserted in the main chamber while pure Ar gas was injected through the hollow cathode with a 28 sccm flow. The differential pumping of the nanoparticle source chamber was throttled to reach a pressure of 130 Pa) in the nanoparticle gun, and a pressure of 0.6 Pa in the main chamber.

One-side polished c-plane sapphire substrates with dimensions of 10×10×0.5 mm³ were used as substrates. The substrates were cleaned with acetone and ethanol in ultrasonic baths for 10 min and were blow-dry using N₂ before being mounted on the substrate holder which was maintained at room temperature and constant rotation during deposition.

The crystal structure of the films was analyzed using a PANAnalytical X'pert powder diffractometer in a Bragg Brentano configuration using a Cu-K α radiation wavelength of 1.5406 Å (45 kV and 40 mA). The measurement scan was recorded with a constant rotation of the sample using a X'celerator detector in 1D scanning line mode: 10-80° 2 θ range, 0.0084° step size, equivalent of 19.7 sec/step.

A scanning electron microscope (ZEISS Gemini SEM 650) operated with an acceleration voltage of 2.00 kV and in-lens detector was used to observe surface morphologies. Thin lamellae were prepared in a FEI Helios NanoLab dual-beam focused ion beam (FIB) microscope, using Ga⁺ ions accelerated at 30 kV, using the standard lift out and thinning procedure. All scanning transmission electron microscopy (STEM) analysis was performed on a FEI Tecnai G2 microscope operated at 200 kV). STEM was combined with both high angle annular dark field (HAADF) and energy dispersive X-ray spectroscopy (EDS) detectors.

The transport properties, *i.e.* electrical conductivity and Seebeck coefficient were measured by the 4-point probe-measurement method in the temperature range 25 – 325 °C using a NETZSCH SBA 458 nemesis. Before the measurement, the chamber was filled with Ar using the standard procedure, *i.e.* the vacuum was applied to the chamber via pumping and filled with argon. This procedure was applied three times to ensure the neutral environment of the chamber. To further evade the risk of pressure accumulation while heating, the chamber was purged with argon gas at the rate of 50 ml/min. The parameters of the maximum current and heater voltage are presented in Table 1. During the measurements, two microheaters generated the temperature gradient in both sample directions (one sample side is being heated and cooled down, and after that, the same applies to another sample side).

A second electrical setup was used to evaluate the resistivity, drift mobility and carrier concentration at room temperature. This homemade setup consists of a Van der Pauw setup adapted for Hall measurement. A Keithley 2400 SourceMeter® and a Keithley 2100 Multimeter® were used to track the current values and measuring voltages, respectively. For the Hall measurement setup, a permanent magnet of 0.5 T was placed and reversed yielding a magnetic field of 0.485 T at the sample position. The Hall measurement was carried out with a constant current of 40 mA where a Labview program was used to select the different measurement configurations necessary for the Hall measurement using the Van der Pauw configuration.

Results and discussions

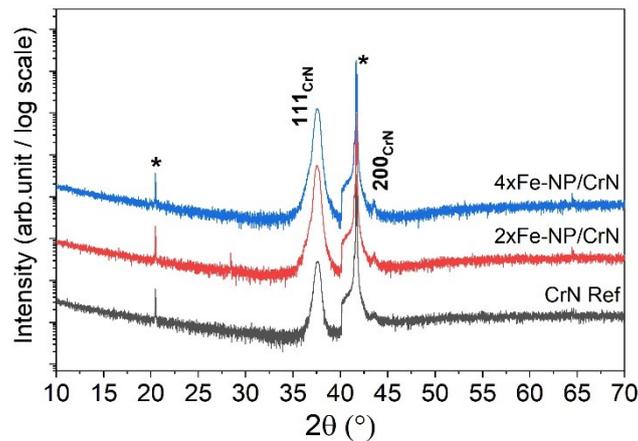


Figure 2: θ - 2θ XRD pattern of the three coatings: the monolithic reference CrN film and the two multilayer coatings with 2 and 4 layers of Fe-NP.

Figure 2 presents the Bragg Brentano θ - 2θ XRD pattern of the reference film and the two multilayer coatings. The substrate peaks from c-plane sapphire were observed at 2θ of 20.5° and 41.6° corresponding to 0003 and 0006 reflection of Al_2O_3 . CrN showed similar features in all films with a preferential orientation along the [111] direction. This preferential orientation of NaCl-B1 CrN on c-plane sapphire is not surprising and has been observed previously[7]. The cell parameter of CrN was estimated at 4.15 \AA for all coatings and was consistent with the experimental and theoretical values reported for CrN [23, 24]. No large differences were noticeable between the two multilayer films except for the increased intensity of the 111 diffraction peak compared to the reference sample. This may originate from variations in the proportion of preferentially oriented grains in the films.

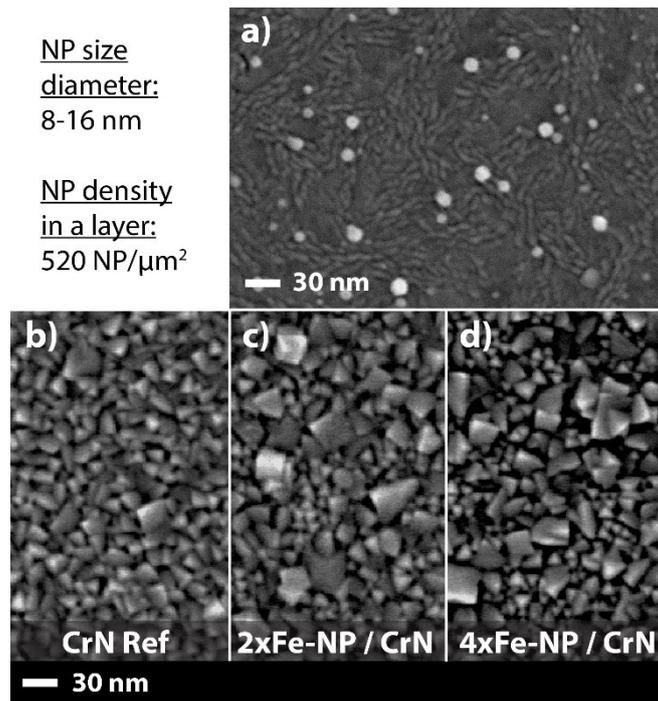


Figure 3: Top surface morphology of a) a typical dispersion of NP on a metal layer (Cr) / deposited in the same condition (time, power) as in the Fe-NP layers in the multilayer coating (Note here the size and density of the NP in one of Fe-NP layer), b) the monolithic CrN films and the two multilayer coatings with c) 2 and d) 4 layers of Fe-NP.

Figure 3 shows the top surface morphology of the reference film, the two multilayer coatings and the Fe NPs deposited in the same conditions as each Fe-NP layer deposited in the multilayer coatings. The nanoparticles had a size ranging between 6 and 13 nm with a spatial density of NP on the film of 520 NP/ μm^2 , approximately (Figure 3a). The reference CrN films had a typical morphology of a cubic NaCl B1 structure material deposited on sapphire. The morphology consisted of pyramidal shape grains (10-15 nm) consistent with the XRD results and the (111) oriented film. Note, that locally some other grain orientations were visible with square-shaped or elongated grains. The two multilayer coatings had similar characteristics as the reference sample but with an increased number of differently oriented grains.

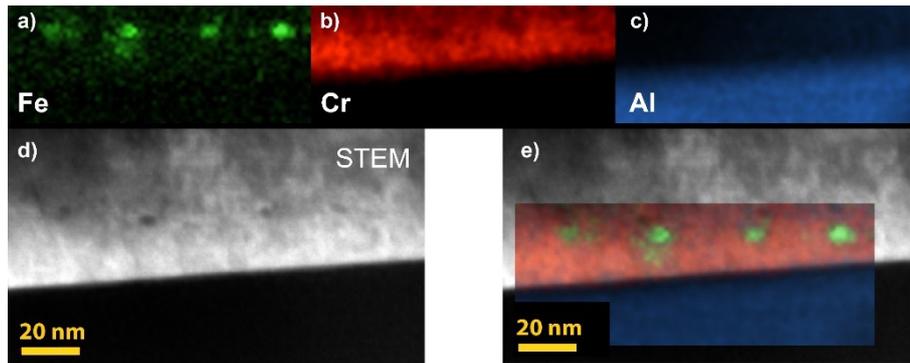


Figure 4: STEM analyses of the 4xFe-NP/CrN film. a), b), c) are the EDS maps of the region of interest with the map corresponding to Fe, Cr, and Al, respectively. e) STEM image of the zone of interest and f) is the superposition of the EDS map on the STEM image.

Figure 4 shows the STEM analyses and EDS maps of a zone of interest of the 4xFe-NP/CrN film. Due to the spatial distribution, size of the NPs and overlapping grains, difficulties were encountered to determining the position of the nanoparticles. Nevertheless, in figure 4, an area is displayed where four NPs were observed using STEM. On the STEM images taken with HAADF detector darker contrast can be distinguished. The EDS map of each element present in the sample (Fe, Cr, Al) confirmed the presence of Fe NPs which appeared to have remained intact during the synthesis process. The size of the NPs was estimated from 6 to 9 nm approximately, consistent with the observations of the Fe-NP morphology made by SEM (Figure 3).

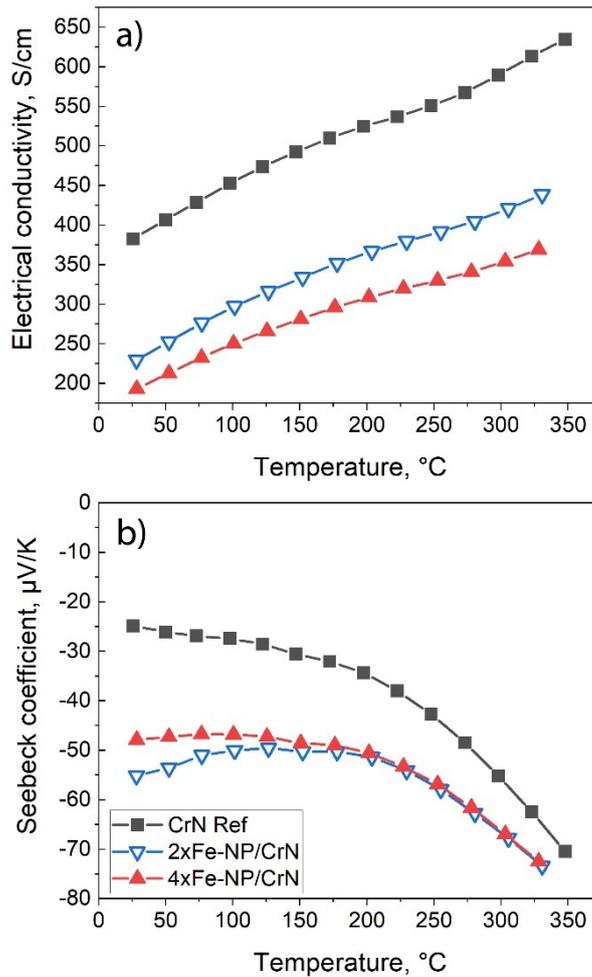


Figure 5: Temperature dependent thermoelectric properties: a) electrical conductivity and b) Seebeck coefficient measured on the CrN reference coating (filled squares) and the two multilayer coatings (2xFe-NP / CrN, empty triangles and 4xFe-NP / CrN, filled triangles).

Figure 5 displays the thermoelectric properties of the three coatings. On the reference sample, both absolute Seebeck values and electrical conductivity increases with temperature from -25 to -70 $\mu\text{V/K}$ and from 375 to 625 S/cm, respectively. The low values for Seebeck coefficient of the reference samples are caused by the crystal quality of the film and the morphology, which differ from other studies [7, 25, 26]. In the present study, the deposition at room temperature led to the NaCl-B1 structure but with small grains sizes, in contrast to the studies reporting rather high thermoelectric properties of CrN with micrometric grain size containing films[7]. The multilayer coatings exhibited higher absolute Seebeck values of 50-60 $\mu\text{V/K}$ and lower electrical conductivity of 200-230 S/cm at room temperature. However, their temperature dependence resembles that of the reference CrN sample. All samples exhibited a semiconductor behavior with an increase of the electrical conductivity with temperature.

Table 2: Room temperature electrical characteristics: electrical resistivity, Seebeck coefficient, charge carrier concentration and charge carrier mobility with the corresponding total thickness of the coating.

Sample	Thickness (nm)	Resistivity (m Ω ·cm) \pm 0.05	Seebeck (μ V/K) \pm 2	Charge carrier mobility (cm ² /Vs) \pm 0.1	Charge carrier concentration (cm ⁻³) \pm 0.1
CrN ref	80	2.54	- 26	0.3	-92.1 \times 10 ²⁰
2xFe-NP / CrN	85	3.28	- 55	2.6	-7.3 \times 10 ²⁰
4xFe-NP / CrN	90	4.26	- 49	2.2	-6.7 \times 10 ²⁰

Table 2 lists the supplementary electrical characteristics of the films such as the carrier concentration and drift mobility measured on the three coatings. The reference sample had a rather high charge carrier concentration around $\sim 92 \times 10^{20} \text{ cm}^{-3}$. This value is larger than the ones reported for CrN ($\sim 0.2\text{-}2 \times 10^{20} \text{ cm}^{-3}$) which, combined with the small grain size of the film, can lead to low Seebeck coefficient values [7, 26]. The electron mobility in the reference sample was in the same order as the ones reported in CrN with a value around $0.3 \text{ cm}^2/\text{Vs}$ [26]. For the two multilayer coatings, the charge carrier concentration dropped by one order of magnitude Fe-NP are embedded into CrN. Their electron drift mobility is one order of magnitude higher than the reference sample.

The strategy employed in the present study for the synthesis of nanocomposite using a combinatorial PVD technique was successful. The Fe NPs remained intact, and no diffusion or reaction seemed to occur between the matrix and the NPs leading to a nanocomposite material. The addition of Fe NPs had an impact on the electrical properties of the films by i) lowering the charge carrier concentration, ii) increasing the electron mobility, iii) yielding an increase of the Seebeck coefficient and reduced electrical conductivity. Quintela *et al.* have reported a study on heavy doping of CrN using Mo or W. They have shown that once the solubility limit is reached, nanoinclusions of metal would form and an increase of the resistivity would be observed. They attributed this deterioration of the electrical behavior to the fact that the nanoinclusions would scatter electrons, hence reduce their mobility. In the present study, the effect of the nanoparticle is not entirely understood as their insertion led to an increase of the electron mobility and a simultaneous reduction of the measured charge carrier concentrations and mobility. The most probable explanation for the increase of the electron mobility together with the diminution of the charge carrier concentration is the energy filtering by internal phases created at interface NP/matrix. This can be triggered when metallic particles are embedded in a TE matrix [27]. In such case, the low-energy electrons are scattered effectively, resulting in enhancement of the Seebeck coefficient, decrease of the measured carrier density and increase of the

mobility[2, 27, 28]. The creation of scattering center for phonons is expected in such nanocomposite materials which should lead to a reduction of the thermal conductivity compared to the reference sample.

Conclusion

Using an approach of multilayer structured films, the effect Fe NP insertion into CrN films on their thermoelectric properties have been studied. The presence of Fe NPs has been confirmed by STEM and EDS mapping where the Fe NP remained intact without noticeable reaction with the matrix. The insertion of Fe NPs into CrN led to an increase of the Seebeck coefficient and a decrease of the electrical conductivity. The variation of electrical behavior has been attributed to the change of the carrier concentration with an increase of the electron mobility. This study revealed the potential of the nanocomposite strategy using magnetic NPs which could lead to significant improvements in the performance of thermoelectric materials. This study also showed the exciting potential of the combined magnetron sputtering – nanoparticle gun approach for the direct synthesis of nanocomposite coatings.

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References

- [1] X. Chen, Z. Zhou, Y.-H. Lin, C. Nan, Thermoelectric thin films: Promising strategies and related mechanism on boosting energy conversion performance, *J. Materiomics*, 6 (2020) 494-512.
- [2] G.J. Snyder, E.S. Toberer, Complex thermoelectric materials, *Nat Mater*, 7 (2008) 105-114.
- [3] Y. Lan, A.J. Minnich, G. Chen, Z. Ren, Enhancement of Thermoelectric Figure-of-Merit by a Bulk Nanostructuring Approach, *Adv. Funct. Mater.*, 20 (2010) 357-376.
- [4] M.N. Hasan, H. Wahid, N. Nayan, M.S. Mohamed Ali, Inorganic thermoelectric materials: A review, *Int. J. Energy Res.*, 44 (2020) 6170-6222.
- [5] N. Jia, J. Cao, X.Y. Tan, J. Dong, H. Liu, C.K.I. Tan, J. Xu, Q. Yan, X.J. Loh, A. Suwardi, Thermoelectric materials and transport physics, *Mater. Today Phys.*, 21 (2021) 100519.
- [6] P. Eklund, S. Kerdsonpanya, B. Alling, Transition-metal-nitride-based thin films as novel energy harvesting materials, *J. Mater. Chem. C*, 4 (2016) 3905-3914.
- [7] M.A. Gharavi, S. Kerdsonpanya, S. Schmidt, F. Eriksson, N.V. Nong, J. Lu, B. Balke, D. Fournier, L. Belliard, A.I. Febvrier, C. Pallier, P. Eklund, Microstructure and thermoelectric properties of CrN and CrN/Cr 2 N thin films, *J. Phys. D: Appl. Phys.*, 51 (2018) 355302.
- [8] A. le Febvrier, D. Gambino, F. Giovannelli, B. Bakhit, S. Hurand, G. Abadias, B. Alling, P. Eklund, p-type behavior of CrN thin films via control of point defects, *Phys. Rev. B*, 105 (2022) 104108.
- [9] B. Biswas, S. Chakraborty, O. Chowdhury, D. Rao, A.I.K. Pillai, V. Bhatia, M. Garbrecht, J.P. Feser, B. Saha, In-plane Cr₂N-CrN metal-semiconductor heterostructure with improved thermoelectric properties, *Phys. Rev. Materials*, (2021).
- [10] C.X. Quintela, F. Rivadulla, J. Rivas, Thermoelectric properties of stoichiometric and hole-doped CrN, *Appl. Phys. Lett.*, 94 (2009) 152103.
- [11] C.X. Quintela, B. Rodríguez-González, F. Rivadulla, Thermoelectric properties of heavy-element doped CrN, *Appl. Phys. Lett.*, 104 (2014) 022103.
- [12] I. Stockem, A. Bergman, A. Glensk, T. Hickel, F. Körmann, B. Grabowski, J. Neugebauer, B. Alling, Anomalous Phonon Lifetime Shortening in Paramagnetic CrN Caused by Spin-Lattice Coupling: A Combined Spin and Ab Initio Molecular Dynamics Study, *Phys. Rev. Lett.*, 121 (2018) 125902.
- [13] D. Rao, B. Biswas, E. Flores, A. Chatterjee, M. Garbrecht, Y.R. Koh, V. Bhatia, A.I.K. Pillai, P.E. Hopkins, M. Martin-Gonzalez, B. Saha, High mobility and high thermoelectric power factor in epitaxial ScN thin films deposited with plasma-assisted molecular beam epitaxy, *Appl. Phys. Lett.*, 116 (2020) 152103.
- [14] W.S. Williams, The thermal conductivity of metallic ceramics, *JOM*, 50 (1998) 62-66.
- [15] S.V. Faleev, F. Léonard, Theory of enhancement of thermoelectric properties of materials with nanoinclusions, *Phys. Rev. B*, 77 (2008) 214304.
- [16] L. Jiangyu, Unexpected boost of thermoelectric performance by magnetic nanoparticles, *Sci. China Mater.*, 60 (2017) 1023.
- [17] W. Zhao, Z. Liu, Z. Sun, Q. Zhang, P. Wei, X. Mu, H. Zhou, C. Li, S. Ma, D. He, P. Ji, W. Zhu, X. Nie, X. Su, X. Tang, B. Shen, X. Dong, J. Yang, Y. Liu, J. Shi, Superparamagnetic enhancement of thermoelectric performance, *Nature*, 549 (2017) 247-251.
- [18] S. Sumithra, N.J. Takas, D.K. Misra, W.M. Nolting, P.F.P. Poudeu, K.L. Stokes, Enhancement in Thermoelectric Figure of Merit in Nanostructured Bi₂Te₃ with Semimetal Nanoinclusions, *Advanced Energy Materials*, 1 (2011) 1141-1147.
- [19] E. Lee, J. Ko, J.-Y. Kim, W.-S. Seo, S.-M. Choi, K.H. Lee, W. Shim, W. Lee, Enhanced thermoelectric properties of Au nanodot-included Bi₂Te₃ nanotube composites, *J. Mater. Chem. C*, 4 (2016) 1313-1319.
- [20] B. Biswas, S. Chakraborty, O. Chowdhury, D. Rao, A.I.K. Pillai, V. Bhatia, M. Garbrecht, J.P. Feser, B. Saha, In-plane $\text{Cr}_2\text{N}/\text{CrN}$ metal-semiconductor heterostructure with improved thermoelectric properties, *Phys. Rev. Mat.*, 5 (2021) 114605.
- [21] R. Shu, Z. Han, A. Elsukova, Y. Zhu, P. Qin, F. Jiang, J. Lu, P.O.Å. Persson, J. Palisaitis, A. le Febvrier, W. Zhang, O. Cojocar-Mirédin, Y. Yu, P. Eklund, W. Liu, Solid-State Janus Nanoprecipitation

Enables Amorphous-Like Heat Conduction in Crystalline Mg₃Sb₂-Based Thermoelectric Materials, *Advanced Science*, 9 (2022) 2202594.

[22] A. le Febvrier, L. Landälv, T. Liersch, D. Sandmark, P. Sandström, P. Eklund, An upgraded ultra-high vacuum magnetron-sputtering system for high-versatility and software-controlled deposition, *Vacuum*, 187 (2021) 110137.

[23] B. Alling, T. Marten, I.A. Abrikosov, Effect of magnetic disorder and strong electron correlations on the thermodynamics of CrN, *Phys. Rev. B*, 82 (2010) 184430.

[24] S. Kerdsonpanya, B. Sun, F. Eriksson, J. Jensen, J. Lu, Y.K. Koh, N.V. Nong, B. Balke, B. Alling, P. Eklund, Experimental and theoretical investigation of Cr_{1-x}Sc_xN solid solutions for thermoelectrics, *J. Appl. Phys.*, 120 (2016) 215103.

[25] C.X. Quintela, J.P. Podkaminer, M.N. Luckyanova, T.R. Paudel, E.L. Thies, D.A. Hillsberry, D.A. Tenne, E.Y. Tsymbal, G. Chen, C.-B. Eom, F. Rivadulla, Epitaxial CrN Thin Films with High Thermoelectric Figure of Merit, *Adv. Mater.*, 27 (2015) 3032-3037.

[26] X.Y. Zhang, J.S. Chawla, B.M. Howe, D. Gall, Variable-range hopping conduction in epitaxial CrN(001), *Phys. Rev. B*, 83 (2011) 165205.

[27] J.-H. Bahk, Z. Bian, A. Shakouri, Electron energy filtering by a nonplanar potential to enhance the thermoelectric power factor in bulk materials, *Phys. Rev. B*, 87 (2013) 075204.

[28] C. Gayner, Y. Amouyal, Energy Filtering of Charge Carriers: Current Trends, Challenges, and Prospects for Thermoelectric Materials, *Adv. Funct. Mater.*, 30 (2020) 1901789.